

INFORMATION DISCLOSURE STATEMENT

Attorney Docket:	P70853US0		
Application No.:	10/554,048		
Filing Date:	October 24, 2005	•	
Inventor:	DOBSCHAL et al.		
Art Unit:	Not Yet Assigned		
Examiner:	Not Yet Assigned		

			U.S. PATENT	DOCUMENTS				
Examiner Initials*	Cite No.	Document Number	Publication Date	Name of Patentee or App	plicant Rel	Relevant Pages, Cols, Lines, Figs.		
FP	AA	US- 5,498,923 A	3/12/96	LA FONTAINE et al.				
FP	AB	US- 3,917,950 A	11/4/75	CARLSON				
FP	AC	US- 6,492,644	12/10/02	STAIB				
FP	AD	US- 2003/0011896 A1	1/16/03	SHIRAISHI				
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FP	AF	US- 2004/0174607 A1	9/9/04	BRUNNER et al.				
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		FO	REIGN PATE	NT DOCUMENTS		·		
Examiner Initials*	Cite No.	Country Code + Number	Publication Date	Name of Patentee or Applicant	Relevant Pages, Cols, Lines, Figs.			
FP	AG	DE 10130212 A1	1/2/03	CARL ZEISS JENA GMBH		SEE AF		
FP	AH	EP 1 063 676 A	12/27/00	STAIB INSTR GMBH		SEE AC		
FP	Al	DE 19929185 A1	6/25/99	STAIB INSTR GMBH		SEE AC		
FP	AJ	DE 10063239 A1	12/19/00	NIKON CORP		SEE AE		
				ATURE DOCUMENTS		Nation III		
Examiner Initials*	Cite No.	Include name of author in CAPS; title of article; title of book, magazine, journal etc.; date; page(s); volume/issue number(s); publisher; city and/country where published.						
FP	AK	IMADA S ET AL; "Epitaxial Growth of Ferroelectric YMnO ₃ thin films on Si (111) Substrates by Molecular Beam Epitaxy"; Japanese Journal of Applied Physics; Publication Office Japanese Journal of Applied Physics; December 1998; pgs. 6497-6501; vol. 37 no. 12A Part 1; Tokyo.						
Examiner Signature		/Fani Boosalis/		Date Considered	01/17/2007			

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP § 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.